L6452

Dual 13x16 Matrix Head Ink Jet Driver

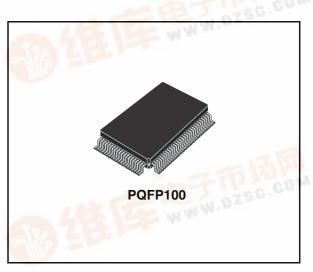
Features

- DRIVES TWO 13X16 MATRIX HEADS
- HEAD TEMPERATURE SENSING ZSG.COM
- POWER UP SYSTEM
- ELECTRICAL NOZZLE CHECK
- 8 BIT A/D
- 5 BIT D/A
- ± 4KV ESD PROTECTED OUTPUTS

Description

L6452 is a device designed to drive two 13x16 matrix ink jet print heads in printer applications.

The output stage is able to source simultaneously 400 mA on each of the 16 power lines (columns) with a duty cycle of 33% in normal printing and 66% in head pre-heating. On the address lines (rows), the load is only capacitive (MOS FET driving capability). The driver can control two print heads, but only one is active at a time. The address scanning counter is included and can be disabled to allow a different scanning scheme.



In order to avoid output activation during the supply transient, an internal power-up system is implemented.

As supporting function, L6452 is capable of sensing the head silicon temperature and to electrically check each nozzle.

The device is also integrating a thermal protection.

Order codes

Part number	Op. Temp range, °C	Package	Packing
E-L6452	0 to 70	PQFP100	Tray
L6452DIE8	0 to 70	DIE	
		441	WWW.DZSC.C



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1 Block diagrams



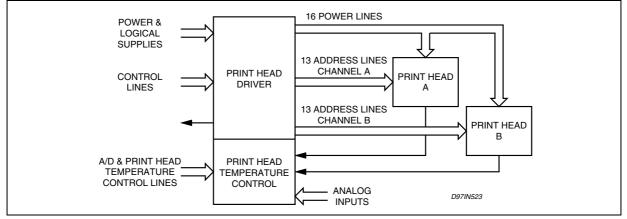
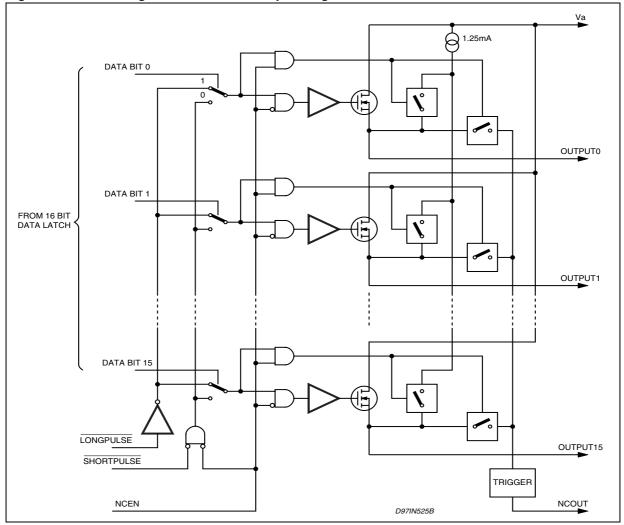


Figure 2. Block Diagram: Power Line Output Stage.



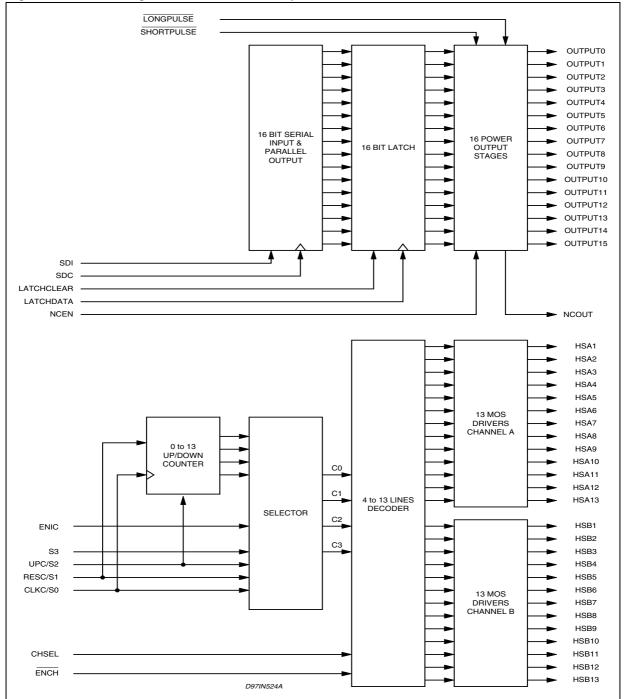


Figure 3. Block Diagram: Nozzle activation part



2 Pin description



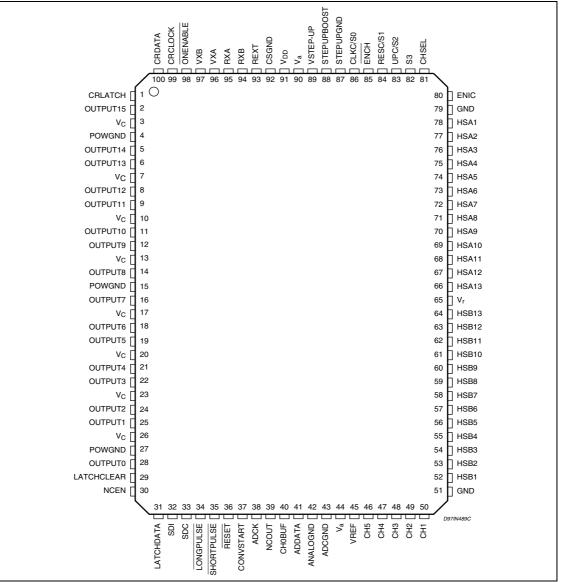


Table 1. Pin function

Pin #	Name	Function
1	CRlatch	A rising edge transfer the information from CR shift register into the control register latching the data on the falling edge
2, 5, 6, 8, 9, 11, 12, 14, 16, 18, 19, 21, 22, 24, 25, 28	Output150	High side DMOS outputs. To be active, ShortPulse and/or LongPulse and NcEn must have a low level

able 1. Pin function - continued			
Pin #	Name	Function	
3, 7, 10, 13, 17, 20, 23, 26	Vc	Outputs Power Supply	
4, 15, 27, 51, 79, 92	GND	logic and power ground	
29	LatchClear	A high level resets all bit in the latch	
30	NcEn	A high level enables the internal current sources and disables all DMOS outputs. To be active, the internal current sources must have their corresponding bit set in the 16 bit latch and LongPulse must be set to low level. This function is called Nozzle Check Enable.	
31	LatchData	A rising edge latches the 16 bit stored in the shift register in the 16 bit latch	
32	SDI	Serial data input of the shift register	
33	SDC	The data bit presented to the SDI pin is stored into the register on the rising edge of this pin	
34	LongPulse	A low level activates all outputs having their corresponding bit in the 16 bit latch set (this pin has an internal pull-up resistor)	
35	ShortPulse	A low level activates all outputs having their corresponding bit in the 16 bit latch reset (this pin has an internal pull-up resistor)	
36	Reset	A low level disables all functions and clears all registers	
37	ConvStart	A high level enables the A/D to start the new conversion	
38	ADCK	A/D clock signal; the ADDATA signal are valid on the falling edge of this pin	
39	NCOut	If NcEn is high this output provides a high level when the open load is detected on the output. If NcEn is low this output provides a high level when a short circuit is detected on HSA/B output	
40	CH0buf	Analog output signal (CH0 buffered)	
41	ADDATA	A/D serial data output	
42	AnalogGND	Analog ground connection	
43	ADCGND	Ground of internal ADC	
44, 90	Va	Power supply	
45	Vref	Reference voltage generator	
46 to 50	CH5CH1	A/D input signals	
52 to 64	HSB1HSB13	Head selector address output channel B	
65	Vr	Head Select Power Supply	
66 to 78	HSA13HSA1	Head selector address output channel A	
80	EnIC	Enable Internal Counter: A high level enables the counter and the internal decoder will activate of the HSx outputs according to the counter's outputs. Signal S0 becomes ClkC and S1 becomes ResC	

F . I. I	D'	
Table 1.	Pin function	- continued



Pin #	Name	Function		
81	ChSel	Channel Select: A low level enables channel A and a high level enables channel B		
82	S3	Decoder input signals when EnIC is low		
83	UpC/S2	UpCount/S2: A high level enables the internal counter to up counting. A low level enables down counting depending on EnIC value it becomes S2.		
84	ResC/S1	Reset Count/S1: A low level resets the internal counter depending on EnIC value it becomes S1.		
85	EnCh	Enable Channel: A low level enables the selected channel (this input has an internal pull up resistor)		
86	ClkC/S0	A high level clocks the internal counter depending on EnIC value it becomes S0.		
87	StepUpGND	Ground of step up block		
88	StepUpBoost	Boost voltage		
89	VstepUp	Driving voltage of power DMOS stage		
91	VDD	5V logic supply		
93	Rext	An external resistor connected to ground fixes the internal current source value		
94, 95	RxB, RxA	Current source outputs		
96, 97	VxA, VxB	RxA, RxB voltage after an optional external filter		
98	OnEnable	A low level enables the current source generator according the \overline{A}/B and ON/ $\overline{O}FF$ control register bit		
99	CRclock	Data on pin CRdata are stored into the register on the rising edge of this pin		
100	CRdata	Control register serial data input		

Table 1.	Pin function - continued



3 Electrical specifications

3.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _c	Power line supply voltage	14	V
Vr	Address line supply voltage	14	V
Va	Analog supply voltage	14	V
V _{dd}	Logic supply voltage	6	V
V _{step_up}	Driving voltage of power DMOS stage	28	V
ESD	In accordance with IEC 1000-4-2 (1)	±4	kV
V _{in}	Logic input voltage range	-0.3 to V _{dd} + 0.3	V
I _{out}	Output continuous current	0.5	Α
Тj	Junction temperature	150	°C
T _{amb}	Operating temperature range	0 to 70	°C
T _{stg}	Storage temperature range	-55 to 150	°C

(1) All the pins connected to the pen passed ESD Contact Electrostatic Discharge @ ±4kV (150pF, 330Ohm source).

3.2 DC Electrical characteristics

Table 3. DC Electrical characteristics ($T_j = 25^{\circ}C$)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _c	Power Line Supply voltage	(1)	10.5 (2)	11.5	12.5	V
V _r	Address line supply voltage	(1)	10.5	11.5	12.5	V
Va	Analog supply voltage	(1)	10.5	11.5	12.5	V
V _{dd}	Logic supply voltage		4.5	5	5.5	V
I _{cs}	V _c sleep supply current				1	mA
I _{rs}	V _r sleep supply current	$\overline{\text{OnEnable}} = 1 \overline{\text{Reset}} = 0$			0.3	mA
I _{as}	V _a sleep supply current				3	mA
Ι _c	V _c supply current				1.5	mA
l _r	V _r supply current				0.6	mA
Ι _a	V _a supply current	I _{Rext} = 3mA			13	mA



Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{dd}	V _{dd} supply current	sleep or normal condition			5	mA
V _{ref}	Reference Voltage	T _{amb} = 5 to 55°C	4.85	5	5.15	V
I _{refext}	Reference current (external)				7	mA
I _{ccs}	Programmed constant current	$I_{ccs} = \frac{V_{ref}}{2R_{ext}} \cdot 4$		12	13.5	mA
$\Delta I_{ccs}/I_{ccs}$	Constant current regulation	$V_a=11V T_{amb} = 5 \text{ to } 55^{\circ}C$		0.33		%
V _{ampout}	Output voltage of integrated		e ⁽³⁾		Va-1	V
	amplifier					
V _{cm}	Operating input voltage at pins	V _{ref} = 5V g1=1.2 g2 = 3			7	V
	Vxa and Vxb					
g1	Amp. A1 Voltage gain		1.188	1.2	1.212	
g2	Amp.A2 Voltage gain		2.95	3.02	3.10	
V _{step-up}	Driving Voltage of power DMOS			Vc +11		V
A/D CONVE	RTER					
V _{A/D in}	A/D input voltage	Selected Channel: CH1 to CH5 Selected Ch=CH0	0 e ⁽³⁾		Vref Vref	V V
I _{exch}	A/D input current	Input CH1 to CH5 selected or not			±1	μA
OFFSET VO	LTAGE GENERATION / DAC			1		1
V _{offset}	Offset Voltage	V _{ref} = 5V	2.5+e <i>(3)</i>		7.34	v
V _{step}	Voltage increment (1LSB)	Vref= 5V		156		mV
K _{dac}	Voffset/Vref	Any step N ≥ 4			±3	%
A/D CONVE	RTER TIMINGS	I				
T _{cscks}	ConvStart set up time		200			ns
T _{csckh}	ConvStart hold time		200			ns
T _{ckout}	Falling edge of clock to data out valid delay	$C_{load} \le 20 pF$			200	ns
T _{csz}	ConvStart falling edge to output in Hi-Z delay				200	ns
F _{adck}	Clock frequency				250	KHz
T _{cslow}	Conv. Start low level time		5.6			μs

Table 3. DC Electrical characteristics ($T_j = 25^{\circ}C$) - continued

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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Uni
T _{acqth}	Theoretical acquisition time	f _{adck} = 250 kHz	32.4			μS
T _{acqpr}	Real acquisition time	f _{adck} = 250 kHz	36			μS
DIGITAL IN	TERFACE INPUT		1			
V _{inp}	Schmitt Trigger positive-going Threshold				2/3V _{dd}	v
V _{inm}	Schmitt Trigger negative-going Threshold		1/3V _{dd}			V
Vhys	Schmitt Trigger Hysteresis		0.1	0.3	1	V
lin	Input Current (Vin=0; V _{dd} =5) ⁽⁴⁾		50	150	300	μA
CR LATCH	TIMINGS					
T _{ls}	Latch set up time		100			ns
T _{lhigh}	Latch high time		100			ns
T _{lconv}	Latch data valid to A/D input valid delay	Selected channel: CH1CH5 CH0	4 7			μS μS
t _{store}	Latching data time		200			ns
T _a	Set up time		35			ns
Τ _b	Hold time		35			115
T _c			00			ns
	Serial clock low time		35			ns
Τ _d	Serial clock low time Serial clock high time					
T _d T _e			35			ns ns
	Serial clock high time		35			ns ns ns ns
T _e	Serial clock high time Serial clock period		35 35 125			ns ns ns ns
T _e T _f	Serial clock high time Serial clock period Latch set up time		35 35 125 100			ns ns ns ns ns
T _e T _f T _g	Serial clock high time Serial clock period Latch set up time Latch data high time NcEn setup time with respect to LongPulse (or ShortPulse)		35 35 125 100 100			ns ns ns
T _e T _f T _g T _{set}	Serial clock high time Serial clock period Latch set up time Latch data high time NcEn setup time with respect to LongPulse (or ShortPulse) Asserted NcEn hold time with respect to LongPulse (or ShortPulse)		35 35 125 100 100 160			ns ns ns ns ns

Table 3.DC Electrical characteristics ($T_j = 25^{\circ}C$) - continued



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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
OUTPUTS E	LECTRICAL CHARACTERISTIC	S		1		1
I _{out}	Output Current (outputs 015)	DC=33%; preheating DC=66%		400		mA
R _{ds(ON)}	On Resistance	T _j = 25°C			1.3	Ω
T _{pdr}	Power output Turn on Time	From 50% LongPulse to 90% power output rising edge Load = 30 Ohm in parallel with 1.5nF			160	ns
T _{pd}	Toff delay time	From 50% LongPulse to 90% power output falling edge Load = 30 Ohm in parallel with 1.5nF			100	ns
R _{pon}	Open Nozzle Check		0.5	1	2	kΩ
	RESS SELECTOR OUTPUT					
T _h	UpC/S2, ResC/S1, ChSel, ClkC/S0 and EnIC set-up time with respect to EnCh		150			ns
T _k	UpC/S2, ResC/S1, ChSel, ClkC/S0 and EnIC hold time with respect to EnCh		50			ns
Тj	UpC/S2 with respect to hold time ClkC/S0		200			ns
Τ _i	UpC/S2 with respect to setup time ClkC/S0		100			ns
Τ _m	Enable input to active output delay time				100	ns
T _n	Clock to active output delay time				150	ns
Τ _ο	Disable input to inactive output delay time				100	ns
f _{clk-counter}	Counter Clock Frequency				1	MHz
Clk _{dc}	Clock duty cycle		10		90	%
T _{on}	Address Turn on time	From 50% ClkC/S0 or selector			325	ns
T _{off}	Address Turn off time	signal to 90% of the address output variation Load: see <i>Figure</i> <i>11.</i>			325	ns

Table 3. DC Electrical characteristics ($T_i = 25^{\circ}C$) - continued

(1) The three supply voltage are independent inside the specified value;

(2) The Min. value for V_c power line has been verified down to 4V in application lab.; nevertheless the parameters are guaranteed within spec limit of the above DC ELECTRICAL CHARACTERISTICS table.

(3) $e = 2 \cdot V_{step}$

(4) This applies to input pins having an internal pull-up (ENCH, LONGPULSE, SHORTPULSE)



3.3 Counter Truth Table

EnIC = 1 UpC/S2 = 1

 $\frac{1}{\text{ResC/S1}} = 1$

Clock Counter	C3	C2	C1	CO
0	0	0	0	0
	0	0	0	1
	0	0	1	1
	0	0	1	0
	0	1	1	0
	0	1	1	1
	0	1	0	1
	0	1	0	0
	1	1	0	0
	1	1	0	1
	1	1	1	1
	1	1	1	0
	1	0	1	0
	1	0	0	0
	0	0	0	0

EnIC = 1UpC/S2 = 0ResC/S1 = 1

Clock Counter	C3	C2	C1	C0
0	0	0	0	0
	1	0	0	0
	1	0	1	0
	1	1	1	0
	1	1	1	1
	1	1	0	1
	1	1	0	0
	0	1	0	0
	0	1	0	1
	0	1	1	1
	0	1	1	0
	0	0	1	0
	0	0	1	1
	0	0	0	1
	0	0	0	0

3.4 Decoder Truth Table

OUTPUTS (HS) ACTIVE	C3*	C2*	C1*	C0*
All inactive	0	0	0	0
1	0	0	0	1
2	0	0	1	1
3	0	0	1	0
4	0	1	1	0
5	0	1	1	1
6	0	1	0	1
7	0	1	0	0
8	1	1	0	0
9	1	1	0	1
10	1	1	1	1
11	1	1	1	0
12	1	0	1	0
13	1	0	0	0
All inactive	1	0	0	1
All inactive	1	0	1	1

* C3 = S3, C2 = S2, C1 = S1, C0 = S0, when EnIC = 0

This table is valid for both Channel A and Channel B and when \overline{EnCh} is set to low level.

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4 Print Head Temperature Control Part

4.1 Introduction

For quality printing, it is necessary to know and control the temperature of the print head. Thus, the latter has a built - in aluminium resistor, whose value changes slightly with the temperature. The temperature determination is done by injecting a constant current in the resistor, and measuring the voltage drop across it. Since high - end printers have two heads, it must also be possible to switch quickly the measurement process from one to the other. The function is foreseen to be integrated into the head driver, and is described hereafter.

4.2 Print Head Block Diagram (*Figure 5.*)

At first we have a constant current source, which can be disabled by an external pin (OnEnable) or by a control register, described later. The value of the current can be programmed by an external resistor, and is given by:

$$I_{CCS} = \frac{V_{ref} \cdot 4}{2 \cdot R_{ext}}$$

This current is injected either into the resistor of the head A (Ralu. A) or B (Ralu. B), depending of the switch SW3. The resistors are grounded, and the voltage at their << hot >> side (Vx) is re-entered via the pins VxA and VxB. Using separate pins from RxA and RxB permits to be more flexible, and a filter can eventually be added as shown in the drawing.

The voltage Vx is amplified by A1 and A2, and then converted in a digital value. To be compatible with the input range of the A/D converter, it is necessary to subtract an offset voltage Voffset from Vx. Moreover, as the initial value of the aluminum resistor is very imprecise. Voffset must be adjustable; this is done by means of a 5 bit - D/A converter, giving 32 different values. Finally, the voltage at the input of the A/D converter is:

$$V_{CH0} = g1 \cdot g2 \cdot VX - g2 \times V_{OFFSET}$$

or

$$V_{CH0} = g1 \cdot g2 \cdot Ralu \cdot I_{CCS} - g2 \cdot V_{OFFSET};$$

$$V_{OFFSET} = V_{REF}/2 + N \cdot V_{REF}/32 N = 0, 1, ...31$$

The reference voltage generator (V_{REF}) is integrated, and used for the current source and both the A/D and D/A converters. In this way, the system performance is independent from the precision of V_{REF} ; this one should, however, be stable. Vref is also available on pin #45, and can be used for low consumption purposes. (The external sinked current has to be a DC current).

The system is under control of a 10 bit register, CR. CR is accessed serially and has a transparent latch, which can be used or not (by trying the latch signal CR latch to V_{CC}).

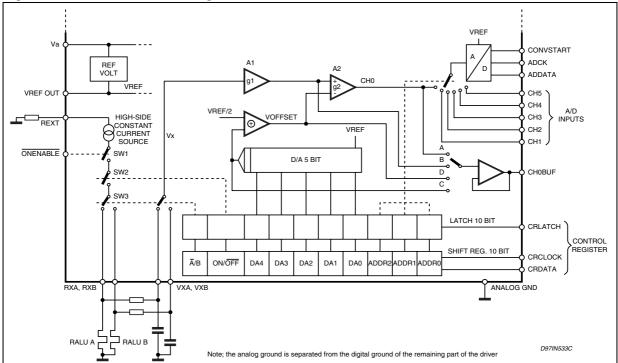
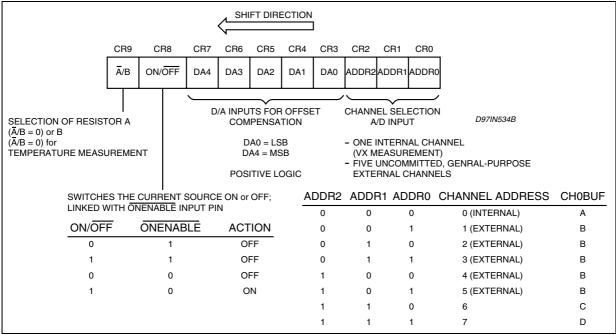


Figure 5. Print Head Block Diagram







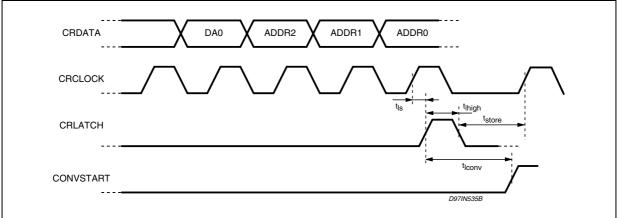


Figure 7. CR Latch Timings



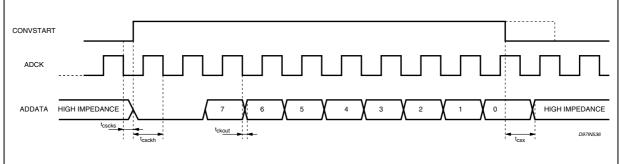


Figure 9. Power Output Timing

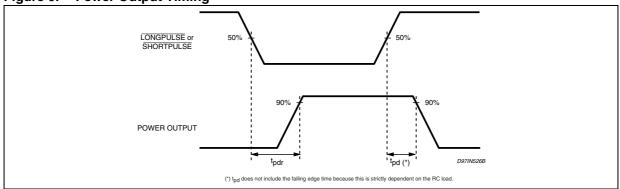


Figure 10. Trigger of Nozzle Check Signal

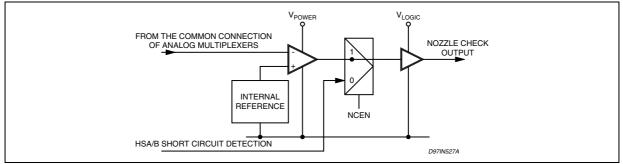


Figure 11. Address load reference

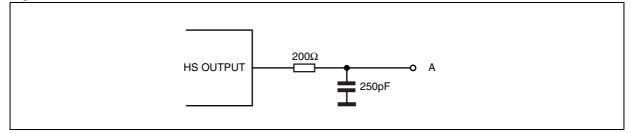
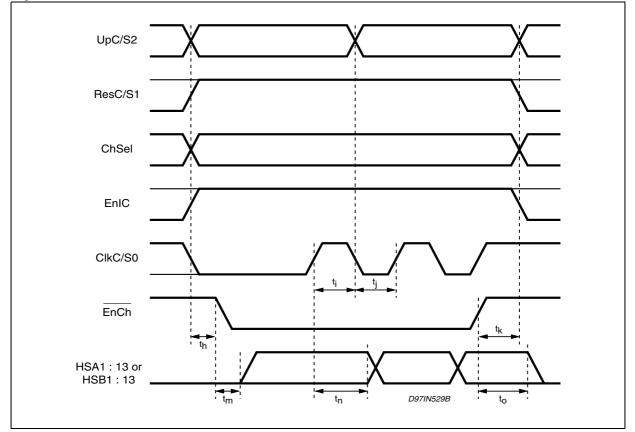


Figure 12. Mode Counter



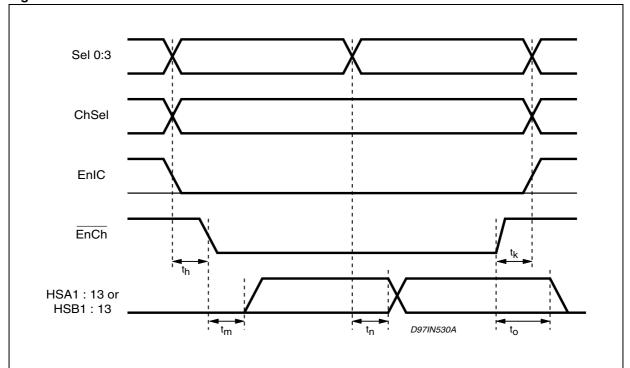




Figure 14. Sequence of Shift Register Data Loading

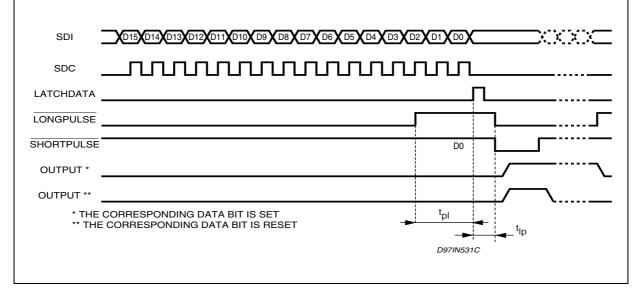
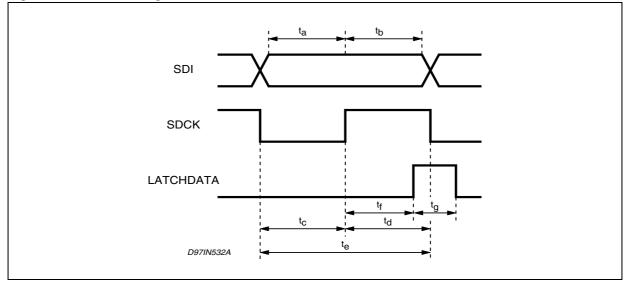


Figure 15. Latch Timing



5 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label.

ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

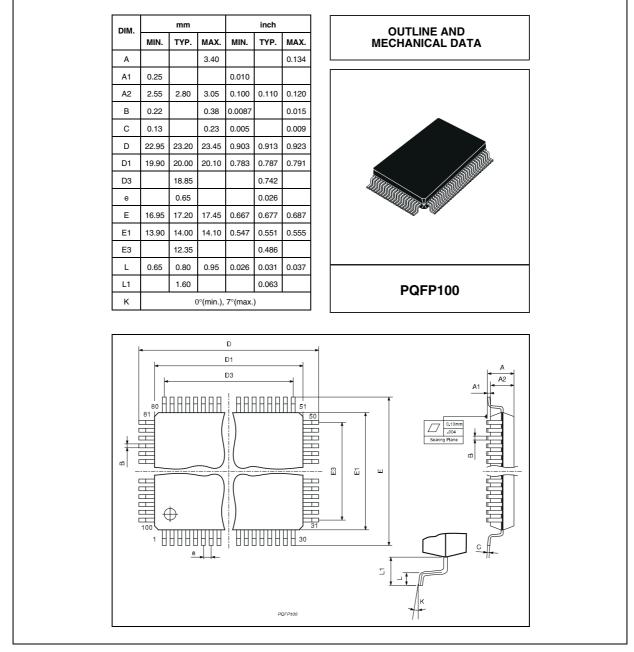


Figure 16. PQFP100 Mechanical Data & Package Dimensions

6 Revision history

Date	Revision	Changes
15-Mar-1999	1	Initial release.
06-Feb-2006	2	Modified Electrical Specification and any Time Diagrams. Modified pin and signal names through out the spec. Modified <i>Table 1</i> Pin function pins 83, 84 & 86. Added ESD parameter in the <i>Table 2</i> Absolute maximum ratings. Modified <i>Table 3</i> : T _{set} , T _{hold} and R _{pon} parameters. Modified <i>Figure 14</i> .

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